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Substitute Form PTO-1449			U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		NAA237	5N 10/573,942		
Information Disclosure Statement					APPLICANT Akinobu Sato, et al.			
					March 29, 2006	GROUP 1723		
			11	C DATENT	DOCUMENTS			
*Exam.	Cite	DOCUMENT NUMBER PUBLICATION NA			ME OF PATENTEE OR APPLICAL	NT	FILING	DATE
Initial	No.	Number - Kind Code US-2008/0315128	12/25/2008	Sato et al.			12/21	/2007
		US-2010/0230616	09/16/2010				04/28/2009	
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*Exam. Cite Include name of the author (in CAPITAL LETTERS), title of the article (when appropri						f the item (book, magazine,	TRANS YES	LATION NO
Illiuai	No.	journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. Panin et al., "p- to n-type Conversion in GaSb by Ion Beam Milling," Appl. Phys. Letters, vol. 67, no.						NO
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